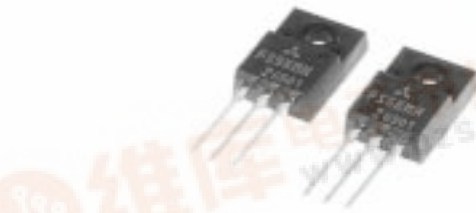


FS5KMH-2

HIGH-SPEED SWITCHING USE

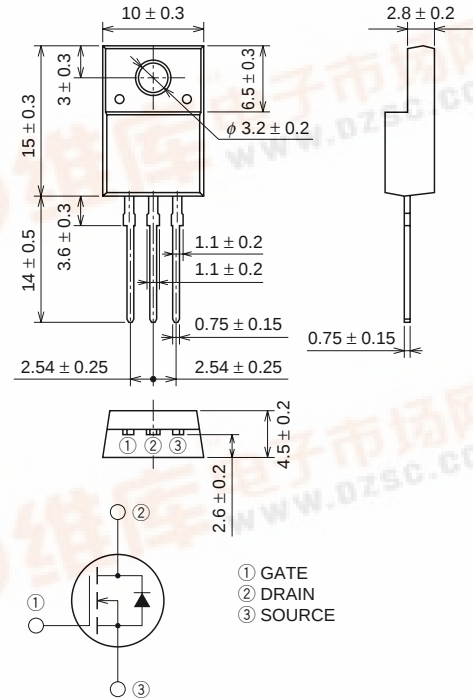
FS5KMH-2



- 2.5V DRIVE
- V_{DS} 100V
- $r_{DS(ON)}$ (MAX) 0.44Ω
- I_D 5A
- Integrated Fast Recovery Diode (TYP.) 80ns
- V_{iso} 2000V

OUTLINE DRAWING

Dimensions in mm



TO-220FN

APPLICATION

Motor control, Lamp control, Solenoid control
DC-DC converter, etc.

MAXIMUM RATINGS (Tc = 25°C)

Symbol	Parameter	Conditions	Ratings	Unit
V_{DS}	Drain-source voltage	$V_{GS} = 0V$	100	V
V_{GS}	Gate-source voltage	$V_{DS} = 0V$	± 10	V
I_D	Drain current		5	A
I_{DM}	Drain current (Pulsed)		20	A
I_{DA}	Avalanche drain current (Pulsed)	$L = 100\mu H$	5	A
I_S	Source current		5	A
I_{SM}	Source current (Pulsed)		20	A
P_D	Maximum power dissipation		15	W
T_{ch}	Channel temperature		$-55 \sim +150$	°C
T_{stg}	Storage temperature		$-55 \sim +150$	°C
V_{iso}	Isolation voltage	AC for 1minute, Terminal to case	2000	V
—	Weight	Typical value	2.0	g

FS5KMH-2

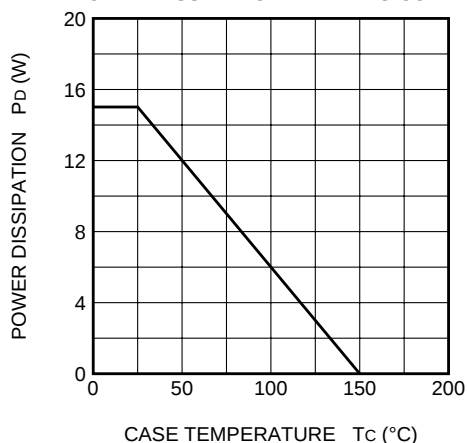
HIGH-SPEED SWITCHING USE

ELECTRICAL CHARACTERISTICS (T_{ch} = 25°C)

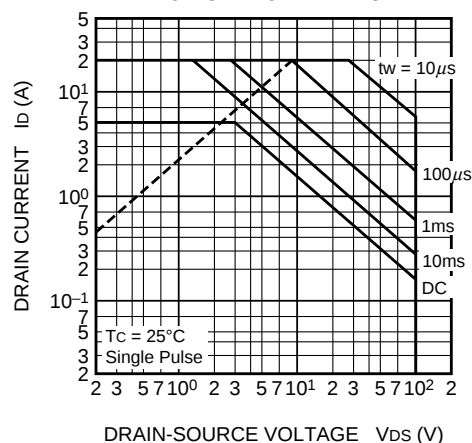
Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V (BR) DSS	Drain-source breakdown voltage	I _D = 1mA, V _{GS} = 0V	100	—	—	V
I _{GSS}	Gate-source leakage current	V _{GS} = ±10V, V _{DS} = 0V	—	—	±0.1	μA
I _{DSS}	Drain-source leakage current	V _{DS} = 100V, V _{GS} = 0V	—	—	0.1	mA
V _{GS} (th)	Gate-source threshold voltage	I _D = 1mA, V _{DS} = 10V	0.6	0.9	1.2	V
r _{DS} (ON)	Drain-source on-state resistance	I _D = 2A, V _{GS} = 4V	—	0.32	0.44	Ω
r _{DS} (ON)	Drain-source on-state resistance	I _D = 2A, V _{GS} = 2.5V	—	0.34	0.47	Ω
V _{DS} (ON)	Drain-source on-state voltage	I _D = 2A, V _{GS} = 4V	—	0.64	0.88	V
y _{fs}	Forward transfer admittance	I _D = 2A, V _{DS} = 5V	—	10	—	S
C _{iss}	Input capacitance	V _{DS} = 10V, V _{GS} = 0V, f = 1MHz	—	540	—	pF
C _{oss}	Output capacitance		—	75	—	pF
C _{rss}	Reverse transfer capacitance		—	20	—	pF
t _d (on)	Turn-on delay time	V _{DD} = 50V, I _D = 2A, V _{GS} = 4V, R _{GEN} = R _{GS} = 50Ω	—	12	—	ns
t _r	Rise time		—	18	—	ns
t _d (off)	Turn-off delay time		—	45	—	ns
t _f	Fall time		—	26	—	ns
V _{SD}	Source-drain voltage	I _S = 2A, V _{GS} = 0V	—	1.0	1.5	V
R _{th} (ch-c)	Thermal resistance	Channel to case	—	—	8.33	°C/W
t _{rr}	Reverse recovery time	I _S = 5A, di _s /dt = -100A/μs	—	80	—	ns

PERFORMANCE CURVES

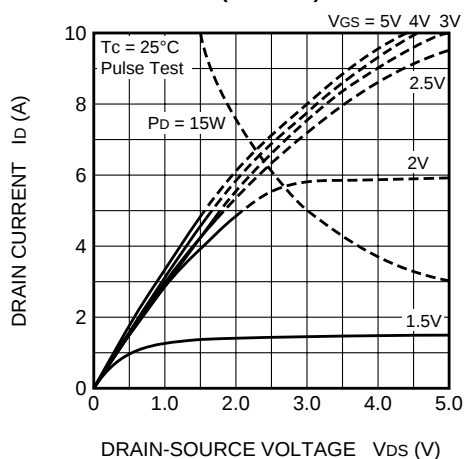
POWER DISSIPATION DERATING CURVE



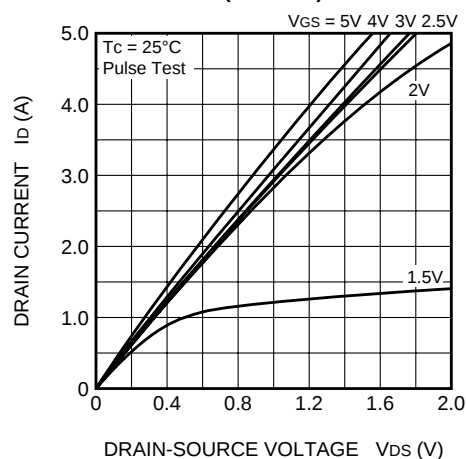
MAXIMUM SAFE OPERATING AREA



OUTPUT CHARACTERISTICS (TYPICAL)

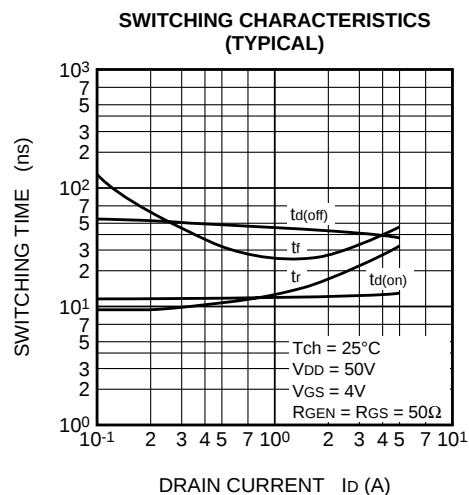
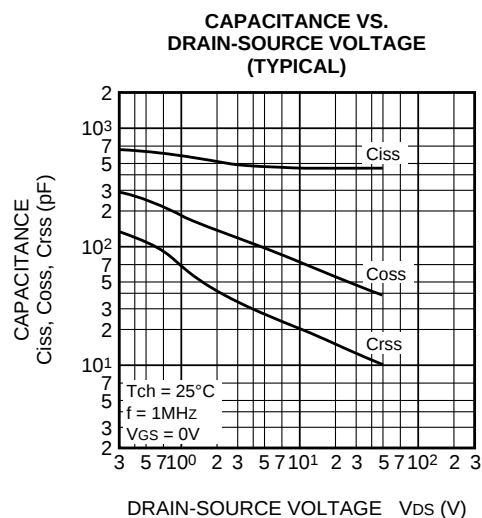
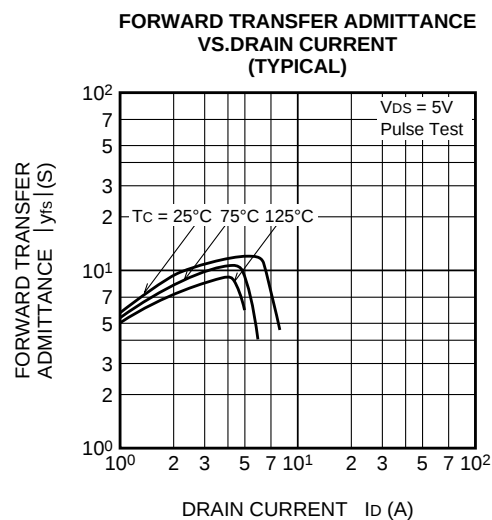
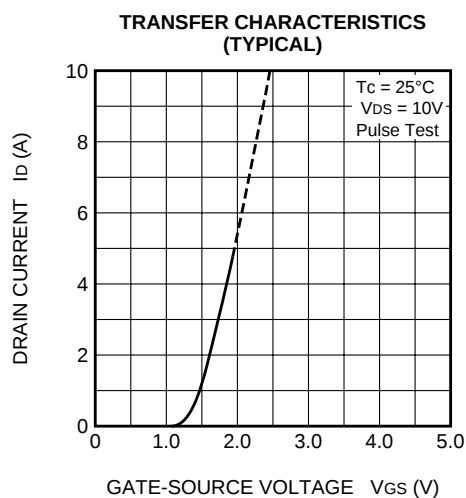
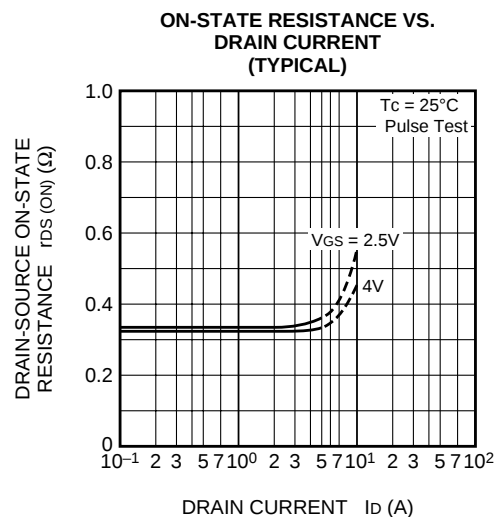
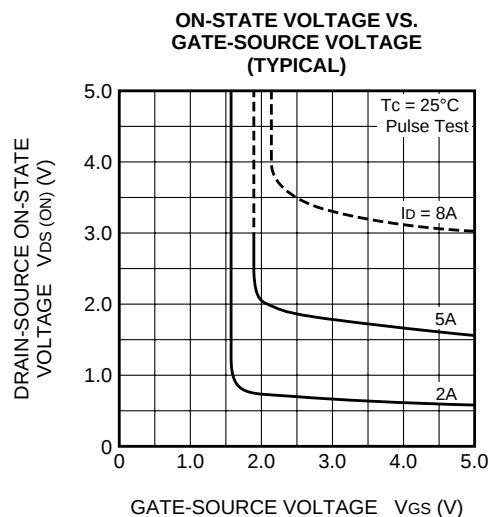


OUTPUT CHARACTERISTICS (TYPICAL)



FS5KMH-2

HIGH-SPEED SWITCHING USE



FS5KMH-2

HIGH-SPEED SWITCHING USE

